

HD74LS283 • 4-bit Binary Full Adders

The HD74LS283 adder is electrically and functionally identical to the HD74LS83A, respectively; only the arrangement of the terminals has been changed.

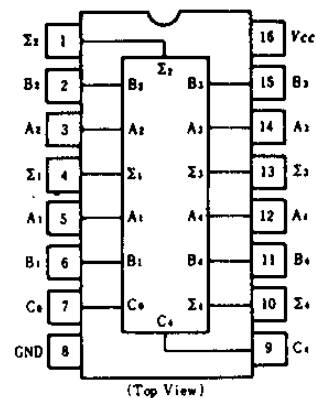
This improved full adder performs the addition of two 4-bit binary words.

The sum (Σ) outputs are provided for each bit and the resultant carry (C_4) is obtained from the fourth bit. This adder features full internal look-ahead across all four bits generating the carry term in then nanoseconds.

The adder logic, including the carry, is implemented in its true form.

End around carry can be accomplished without the need for logic or level inversion.

PIN ARRANGEMENT



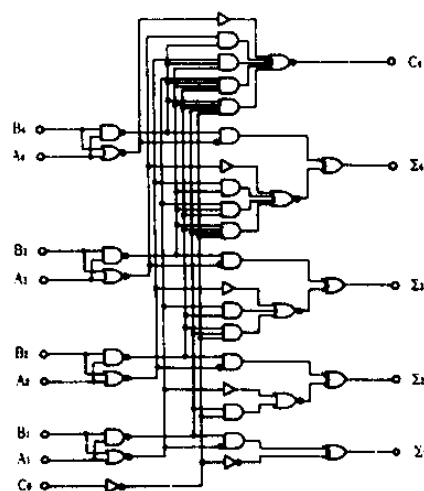
FUNCTION TABLE

Inputs				Outputs					
				When $C_0 = L$		When $C_0 = H$		When $C_0 = L$	
A_1	B_1	A_2	B_2	Σ_1	Σ_2	C_2	Σ_1	Σ_2	C_2
A_3	B_3	A_4	B_4	Σ_3	Σ_4	C_4	Σ_3	Σ_4	C_4
L	L	L	L	L	L	L	H	L	L
H	L	L	L	H	L	L	L	H	L
L	H	L	L	H	L	L	L	H	L
H	H	L	L	L	H	L	H	H	L
L	L	H	L	L	H	L	H	H	L
H	L	H	L	H	H	L	L	L	H
L	H	H	L	H	H	L	L	L	H
H	H	H	L	L	L	H	H	L	H
L	L	L	H	L	H	L	H	H	L
H	L	L	H	H	H	L	L	L	H
L	H	L	H	H	H	L	L	L	H
H	H	L	H	L	L	H	H	L	H
L	L	H	H	L	L	H	H	L	H
H	L	H	H	H	L	H	L	H	H
L	H	H	H	H	L	H	L	H	H
H	H	H	H	L	H	H	H	H	H

H; high level, L; low level

Notes) Input conditions at A_1 , B_1 , A_2 , B_2 , and C_0 are used to determine outputs Σ_1 and Σ_2 and the value of the internal carry C_2 . The values at C_2 , A_3 , B_3 , A_4 , and B_4 are then used to determine outputs Σ_3 , Σ_4 , and C_4 .

BLOCK DIAGRAM



HD74LS283

■ ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$)

Item		Symbol	Test Conditions	min	typ*	max	Unit
Input voltage		V_{IH}		2.0	—	—	V
		V_{IL}		—	—	0.8	V
Output voltage		V_{OH}	$V_{CC}=4.75\text{V}$, $V_{IH}=2\text{V}$, $V_{IL}=0.8\text{V}$, $I_{OH}=-400\mu\text{A}$	2.7	—	—	V
		V_{OL}	$V_{CC}=4.75\text{V}$, $V_{IH}=2\text{V}$, $V_{IL}=0.8\text{V}$	—	—	0.4	V
						0.5	
Input current	except C_0	I_{IH}	$V_{CC}=5.25\text{V}$, $V_i=2.7\text{V}$	—	—	40	μA
	C_0			—	—	20	
	except C_0	I_{IL}	$V_{CC}=5.25\text{V}$, $V_i=0.4\text{V}$	—	—	-0.8	mA
	C_0			—	—	-0.4	
	except C_0	I_I	$V_{CC}=5.25\text{V}$, $V_i=7\text{V}$	—	—	0.2	mA
	C_0			—	—	0.1	
Short-circuit output current		I_{OS}	$V_{CC}=5.25\text{V}$	-20	—	-100	mA
Supply current		I_{CC}	$V_{CC}=5.25\text{V}$	All inputs grounded	22	39	mA
				All B low, other inputs at 4.5V	19	34	
				All inputs at 4.5V	19	34	
Input clamp voltage		V_{IK}	$V_{CC}=4.75\text{V}$, $I_{IS}=-18\text{mA}$	—	—	-1.5	V

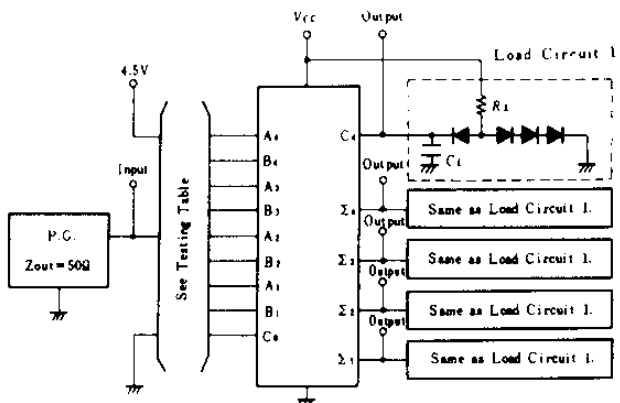
* $V_{CC}=5\text{V}$, $T_a=25^\circ\text{C}$

■ SWITCHING CHARACTERISTICS ($V_{CC}=5\text{V}$, $T_a=25^\circ\text{C}$)

Item	Symbol	Inputs	Outputs	Test Conditions	min	typ	max	Unit
Propagation delay time	t_{PLH}	C_0	Σi	$C_L=15\text{pF}, R_L=2\text{k}\Omega$	—	16	24	ns
	t_{PHL}				—	15	24	ns
	t_{PLH}	A_i, B_i	Σi		—	15	24	ns
	t_{PHL}				—	15	24	ns
	t_{PLH}	C_0	C_4		—	11	17	ns
	t_{PHL}				—	11	22	ns
	t_{PLH}	A_i, B_i	C_4		—	11	17	ns
	t_{PHL}				—	12	17	ns

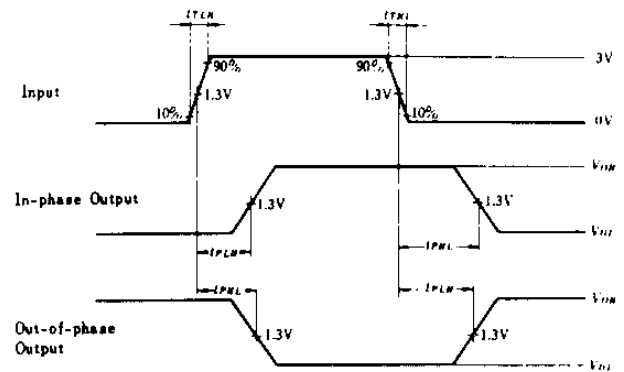
■ TESTING METHOD

1) Test Circuit



- Notes) 1. C_L includes probe and jig capacitance.
2. All diodes are 1S2074 (H).

Waveform

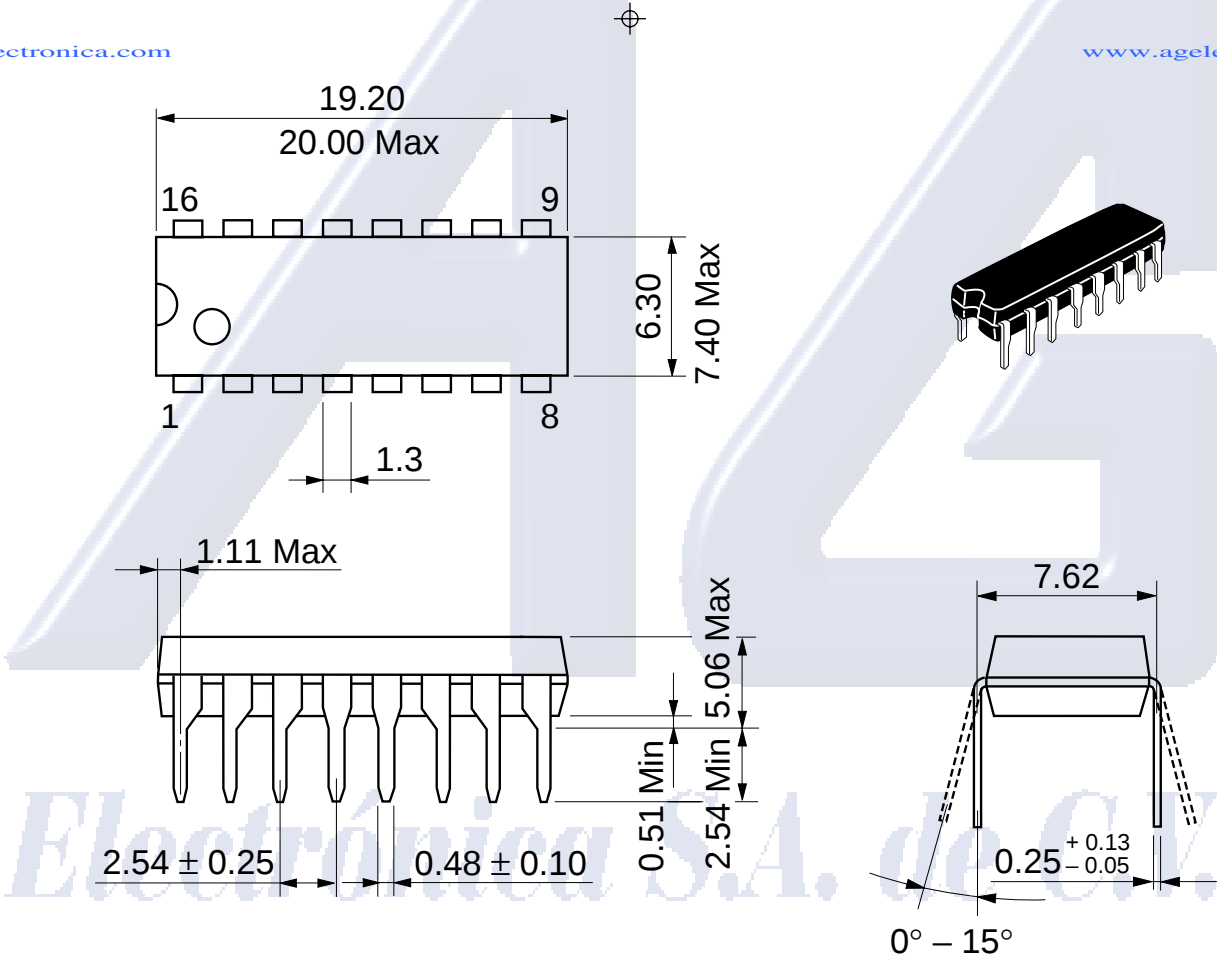


Input pulse; $t_{TLH} \leq 15\text{ns}$, $t_{THL} \leq 6\text{ns}$,
 $PRR=1\text{MHz}$, duty cycle 50%.

2) Testing Table

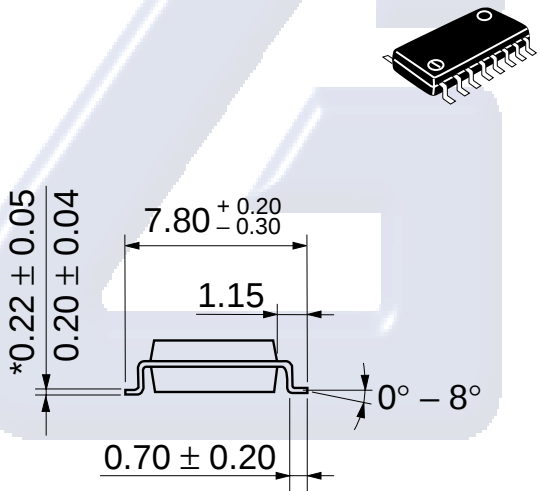
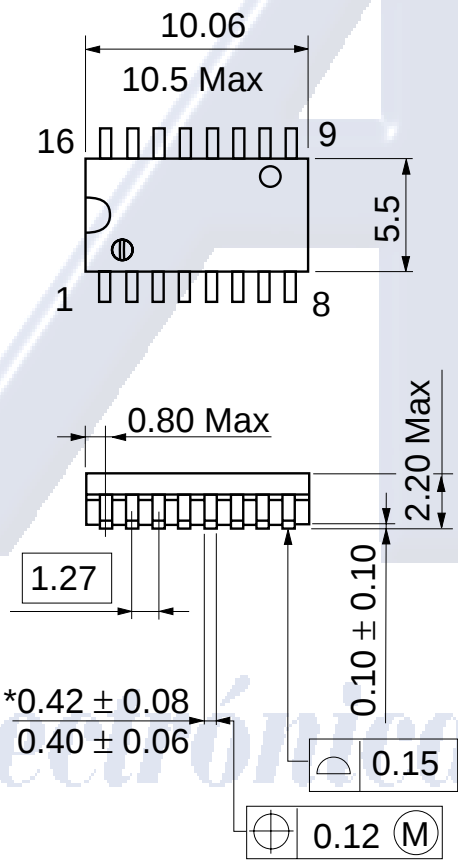
Item	From input to output	Inputs									Outputs				
		B ₄	A ₄	B ₃	A ₃	B ₂	A ₂	B ₁	A ₁	C ₀	C ₄	Σ ₄	Σ ₃	Σ ₂	Σ ₁
t _{PLH} t _{PHL}	Co → Σ _i or C ₄	GND	GND	GND	GND	GND	GND	GND	GND	IN	—	—	—	—	OUT
		GND	4.5V	GND	4.5V	GND	4.5V	GND	4.5V	IN	OUT	OUT	OUT	OUT	OUT
	A _i or B _i → Σ _i or C ₄	GND	GND	GND	GND	GND	GND	GND	IN	GND	—	—	—	—	OUT
		GND	GND	GND	GND	GND	IN	GND	GND	GND	—	—	—	OUT	—
		GND	GND	GND	IN	GND	GND	GND	GND	GND	—	—	OUT	—	—
		GND	IN	GND	GND	GND	GND	GND	GND	GND	—	OUT	—	—	—
		IN	GND	GND	GND	GND	GND	GND	GND	GND	—	—	—	—	—
		GND	GND	GND	GND	GND	GND	4.5V	IN	GND	—	—	—	OUT	OUT
		GND	GND	GND	GND	4.5V	IN	GND	GND	GND	—	—	OUT	OUT	—
		GND	GND	4.5V	IN	GND	GND	GND	GND	GND	—	OUT	OUT	—	—
		4.5V	IN	GND	GND	GND	GND	GND	GND	GND	OUT	OUT	—	—	—
		IN	4.5V	GND	GND	GND	GND	GND	GND	GND	OUT	OUT	—	—	—

Unit: mm



Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

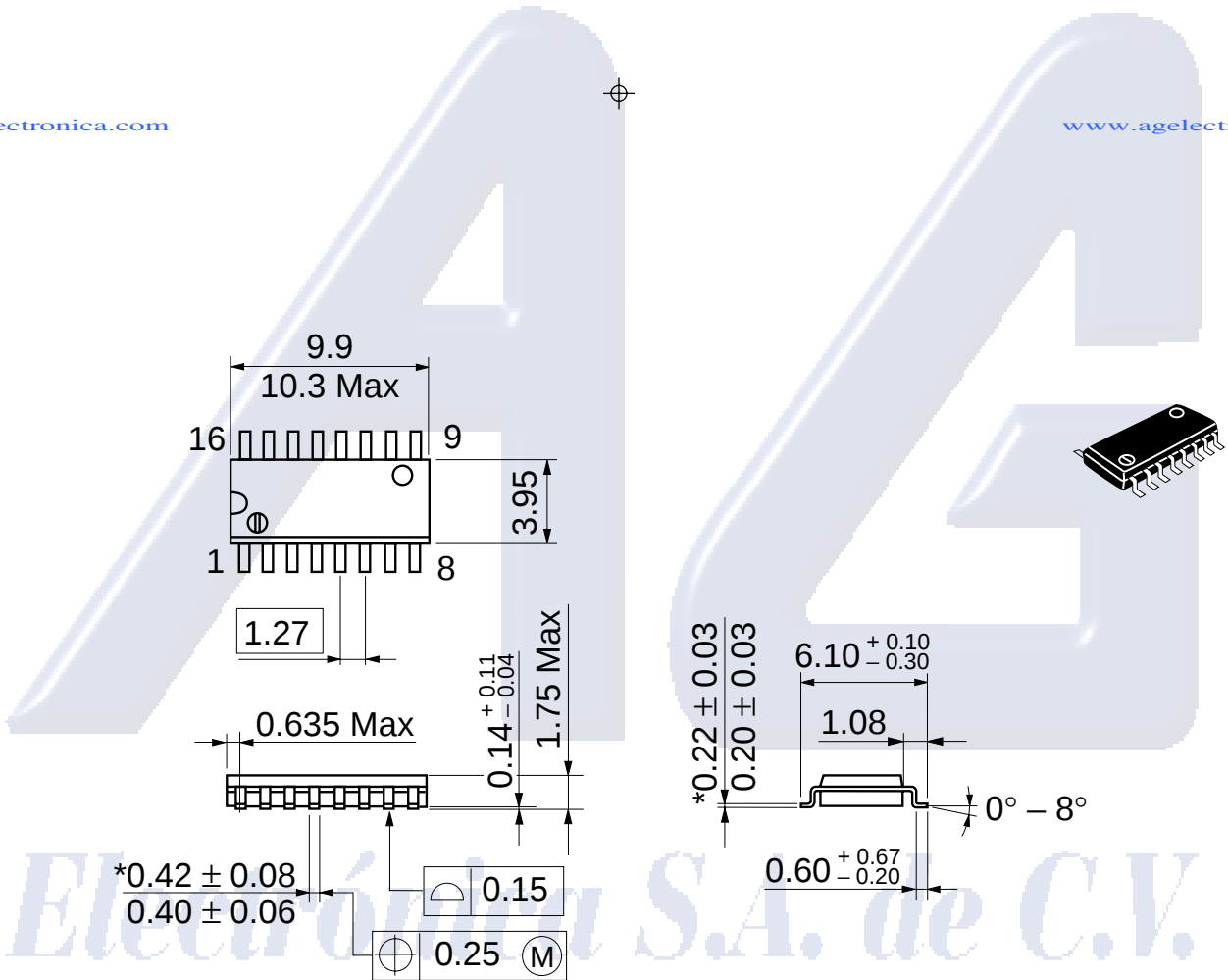
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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